

Transistors

<MOSFET and Di>

Parameter	Symbol	Limits	Unit
Power dissipation	P_D *1	1.0	W / TOTAL
Range of storage temperature	Tstg	-55 to +150	°C

*1 Mounted on a ceramic board

●Electrical characteristics (Ta=25°C)

<MOSFET>

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Gate-source leakage	I_{GSS}	—	—	±10	μA	$V_{GS} = \pm 12V$, $V_{DS} = 0V$
Drain-source breakdown voltage	$V_{(BR) DSS}$	30	—	—	V	$I_D = 1mA$, $V_{GS} = 0V$
Zero gate voltage drain current	I_{DSS}	—	—	1	μA	$V_{DS} = 30V$, $V_{GS} = 0V$
Gate threshold voltage	$V_{GS(th)}$	0.5	—	1.5	V	$V_{DS} = 10V$, $I_D = 1mA$
Static drain-source on-state resistance	$R_{DS(on)}$ *	—	170	240	mΩ	$I_D = 1.5A$, $V_{GS} = 4.5V$
		—	180	250	mΩ	$I_D = 1.5A$, $V_{GS} = 4V$
		—	240	340	mΩ	$I_D = 1.5A$, $V_{GS} = 2.5V$
Forward transfer admittance	$ Y_{fs} $ *	1.5	—	—	S	$V_{DS} = 10V$, $I_D = 1.5A$
Input capacitance	C_{iss}	—	80	—	pF	$V_{DS} = 10V$
Output capacitance	C_{oss}	—	14	—	pF	$V_{GS} = 0V$
Reverse transfer capacitance	C_{rss}	—	12	—	pF	$f = 1MHz$
Turn-on delay time	$t_{d(on)}$ *	—	7	—	ns	$V_{DD} = 15V$ $I_D = 0.75A$
Rise time	t_r *	—	9	—	ns	$V_{GS} = 4.5V$
Turn-off delay time	$t_{d(off)}$ *	—	15	—	ns	$R_L = 20\Omega$
Fall time	t_f *	—	6	—	ns	$R_E = 10\Omega$
Total gate charge	Q_g *	—	1.6	2.2	nC	$V_{DD} = 15V$, $V_{GS} = 4.5V$
Gate-source charge	Q_{gs} *	—	0.5	—	nC	$I_D = 1.5A$
Gate-drain charge	Q_{gd} *	—	0.3	—	nC	$R_L = 10\Omega$, $R_E = 10\Omega$

*Pulsed

<Body diode characteristics (Source-drain)>

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Forward voltage	V_{SD}	—	—	1.2	V	$I_S = 0.6A$, $V_{GS} = 0V$

<Di>

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Forward voltage	V_F	—	—	0.49	V	$I_F = 0.7A$
Reverse current	I_R	—	—	200	μA	$V_R = 20V$

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●Electrical characteristics curves

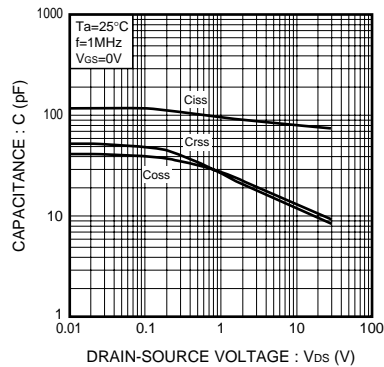


Fig.1 Typical Capacitance vs. Drain-Source Voltage

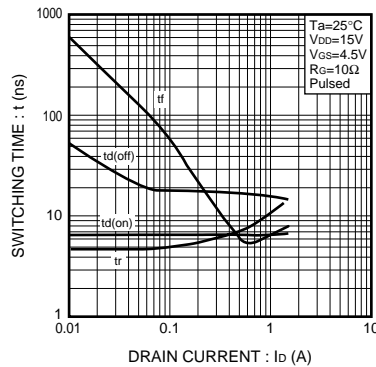


Fig.2 Switching Characteristics

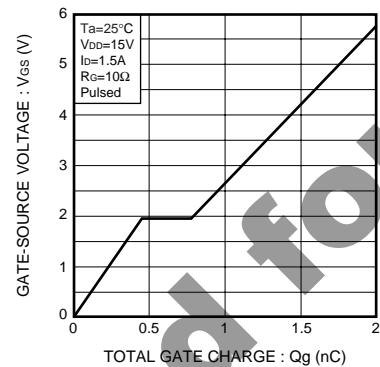


Fig.3 Dynamic Input Characteristics

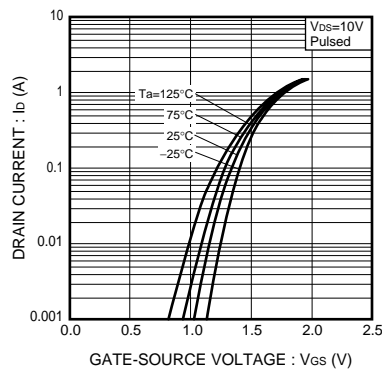


Fig.4 Typical Transfer Characteristics

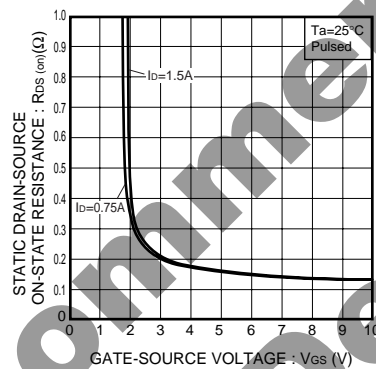


Fig.5 Static Drain-Source On-State Resistance vs. Gate source Voltage

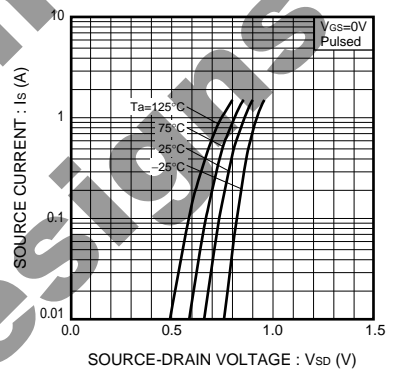


Fig.6 Source Current vs. Source-Drain Voltage

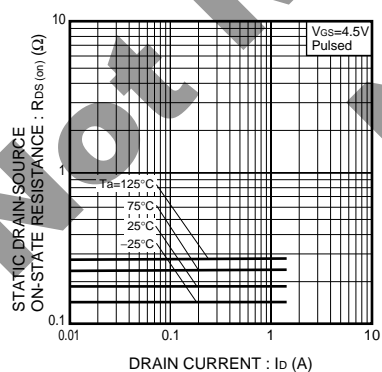


Fig.7 Static Drain-Source On-State Resistance vs. Drain Current (I)

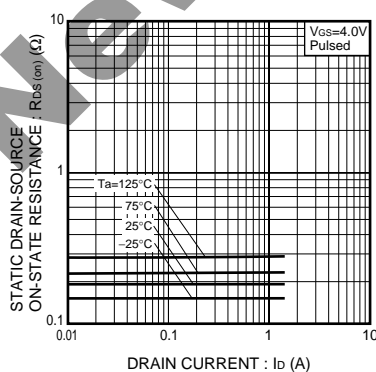


Fig.8 Static Drain-Source On-State Resistance vs. Drain Current (II)

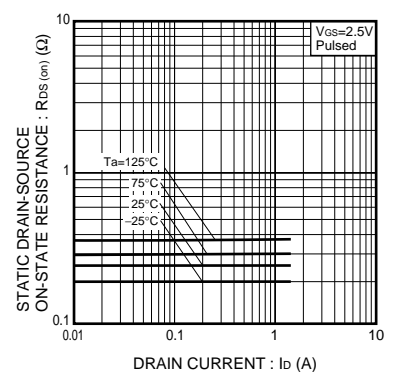


Fig.9 Static Drain-Source On-State Resistance vs. Drain Current (III)

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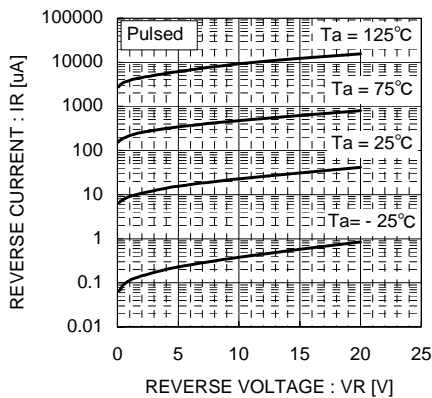


Fig.10 Reverse Current vs. Reverse

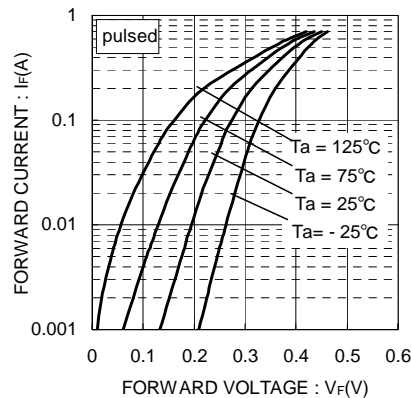


Fig.11 Forward Current vs. Forward Voltage

●Measurement circuit

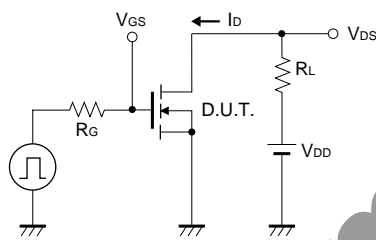


Fig.12 Switching Time Test Circuit

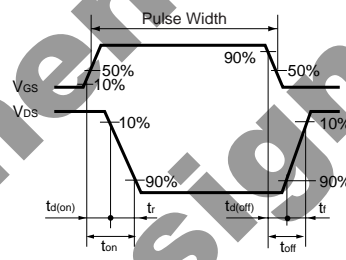


Fig.13 Switching Time Waveforms

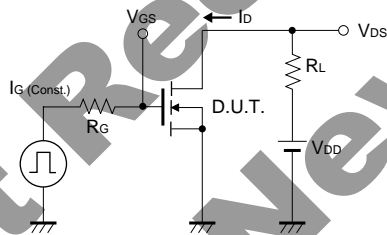


Fig.14 Gate Charge Measurement Circuit

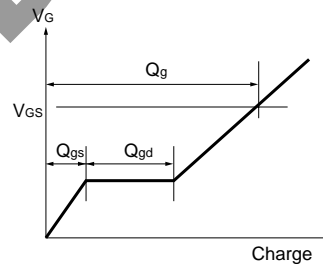


Fig.15 Gate Charge Waveform

●Notice

1. SBD has a large reverse leak current compared to other type of diode. Therefore; it would raise a junction temperature, and increase a reverse power loss. Further rise of inside temperature would cause a thermal runaway. This built-in SBD has low V_F characteristics and therefore, higher leak current. Please consider enough the surrounding temperature, generating heat of MOSFET and the reverse current.
2. This product might cause chip aging and breakdown under the large electrified environment. Please consider to design ESD protection circuit.

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